



ESD



TVS



MOS



LDO



Diode



Sensor



DC-DC

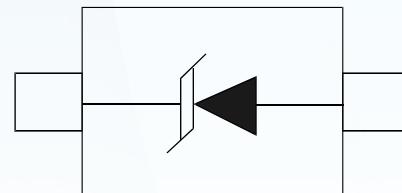
## Product Specification

▶ Domestic Part Number	PESDxxxS1UB
▶ Overseas Part Number	PESDxxxS1UB
▶ Equivalent Part Number	PESDxxxS1UB



## General description

Unidirectional ESD protection diode in a SOD523 plastic package designed to protect one transmission or data line from the damage caused by ESD (ElectroStatic Discharge) and other transients.



## Features

- Unidirectional ESD protection of one line
- Max. peak pulse power:  $P_{PP} = 330 \text{ W}$  at  $t_p = 8/20 \mu\text{s}$
- Low clamping voltage:  $V_{CL} = 20 \text{ V}$  at  $I_{PP} = 18 \text{ A}$
- Ultra low leakage current:  $I_{RM} < 700 \text{ nA}$
- ESD protection  $> 23 \text{ kV}$
- IEC 61000-4-2, level 4 (ESD)
- IEC 61000-4-5 (surge);  $I_{PP} = 18 \text{ A}$  at  $t_p = 8/20 \mu\text{s}$

## Applications

- Computers and peripherals
- Communication systems
- Audio and video equipment
- Data lines
- CAN bus protection

## Quick reference data

### Quick reference data

Symbol	Parameter	Conditions	Value	Unit
$V_{RWM}$	reverse standoff voltage			
	PESD3V3S1UB		3.3	V
	PESD5V0S1UB		5	V
	PESD12VS1UB		12	V
	PESD15VS1UB		15	V
	PESD24VS1UB		24	V

**Quick reference data ...continued**

<b>Symbol</b>	<b>Parameter</b>	<b>Conditions</b>	<b>Value</b>	<b>Unit</b>
$C_d$	diode capacitance	$V_R = 0 \text{ V}; f = 1 \text{ MHz}$		
	PESD3V3S1UB		207	pF
	PESD5V0S1UB		152	pF
	PESD12VS1UB		38	pF
	PESD15VS1UB		32	pF
	PESD24VS1UB		23	pF
	number of protected lines		1	

**Limiting values****Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134).

<b>Symbol</b>	<b>Parameter</b>	<b>Conditions</b>	<b>Min</b>	<b>Max</b>	<b>Unit</b>
$P_{PP}$	peak pulse power	8/20 $\mu\text{s}$	[1]		
	PESD3V3S1UB		-	330	W
	PESD5V0S1UB		-	260	W
	PESD12VS1UB		-	180	W
	PESD15VS1UB		-	160	W
	PESD24VS1UB		-	160	W
$I_{PP}$	peak pulse current	8/20 $\mu\text{s}$	[1]		
	PESD3V3S1UB		-	18	A
	PESD5V0S1UB		-	15	A
	PESD12VS1UB		-	5	A
	PESD15VS1UB		-	5	A
	PESD24VS1UB		-	3	A
$T_j$	junction temperature		-	150	$^{\circ}\text{C}$
$T_{amb}$	operating ambient temperature		-65	+150	$^{\circ}\text{C}$
$T_{stg}$	storage temperature		-65	+150	$^{\circ}\text{C}$

[1] Non-repetitive current pulse 8/20  $\mu\text{s}$  exponentially decay waveform; see Figure 1.

**ESD maximum ratings**

Symbol	Parameter	Conditions	[1]	Min	Max	Unit
ESD	electrostatic discharge capability	IEC 61000-4-2 (contact discharge)	[1]			
	PESD3V3S1UB			-	30	kV
	PESD5V0S1UB			-	30	kV
	PESD12VS1UB			-	30	kV
	PESD15VS1UB			-	30	kV
	PESD24VS1UB			-	23	kV
	PESDxS1UB series	HBM MIL-STD883		-	10	kV

[1] Device stressed with ten non-repetitive ElectroStatic Discharge (ESD) pulses; see Figure 2.

**ESD standards compliance**

Standard	Conditions
IEC 61000-4-2, level 4 (ESD)	> 15 kV (air); > 8 kV (contact)
HBM MIL-STD883, class 3	> 4 kV

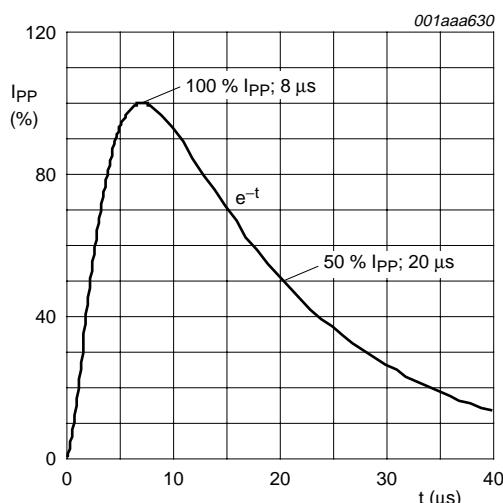


Fig 1. 8/20  $\mu$ s pulse waveform according to IEC 61000-4-5

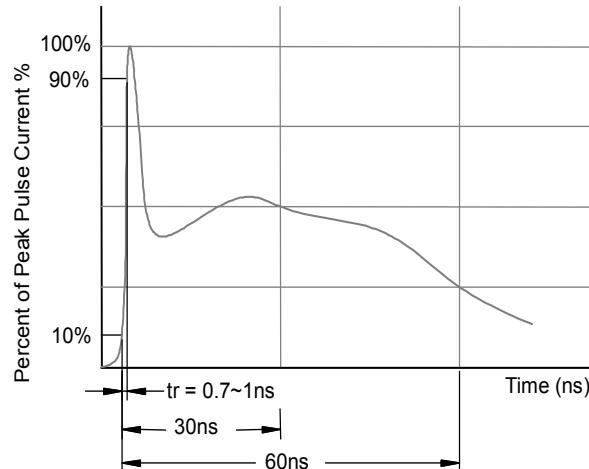


Fig 2. ElectroStatic Discharge (ESD) pulse waveform according to IEC 61000-4-2

## Characteristics

### Characteristics

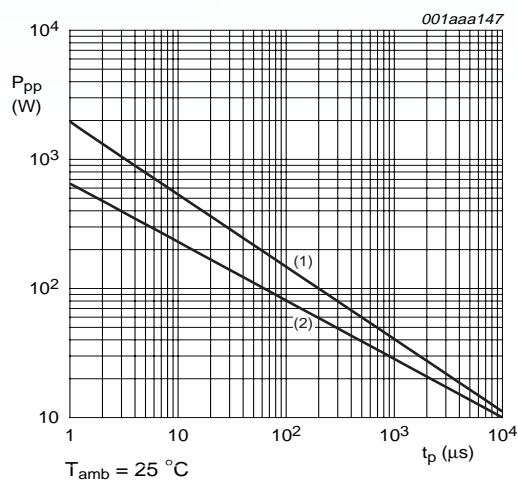
$T_{amb} = 25^\circ\text{C}$  unless otherwise specified

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$V_{RWM}$	reverse standoff voltage					
	PESD3V3S1UB		-	-	3.3	V
	PESD5V0S1UB		-	-	5	V
	PESD12VS1UB		-	-	12	V
	PESD15VS1UB		-	-	15	V
	PESD24VS1UB		-	-	24	V
$I_{RM}$	reverse leakage current	see Figure 7				
	PESD3V3S1UB	$V_{RWM} = 3.3\text{ V}$	-	0.7	2	$\mu\text{A}$
	PESD5V0S1UB	$V_{RWM} = 5\text{ V}$	-	0.1	1	$\mu\text{A}$
	PESD12VS1UB	$V_{RWM} = 12\text{ V}$	-	< 1	50	nA
	PESD15VS1UB	$V_{RWM} = 15\text{ V}$	-	< 1	50	nA
	PESD24VS1UB	$V_{RWM} = 24\text{ V}$	-	< 1	50	nA
$V_{BR}$	breakdown voltage	$I_R = 5\text{ mA}$				
	PESD3V3S1UB		5.2	5.6	6.0	V
	PESD5V0S1UB		6.4	6.8	7.2	V
	PESD12VS1UB		14.7	15.0	15.3	V
	PESD15VS1UB		17.6	18.0	18.4	V
	PESD24VS1UB		26.5	27.0	27.5	V
$C_d$	diode capacitance	$V_R = 0\text{ V}; f = 1\text{ MHz};$ see Figure 5 and 6				
	PESD3V3S1UB		-	207	300	pF
	PESD5V0S1UB		-	152	200	pF
	PESD12VS1UB		-	38	75	pF
	PESD15VS1UB		-	32	70	pF
	PESD24VS1UB		-	23	50	pF
$V_{(CL)R}$	clamping voltage		[1]			
	PESD3V3S1UB	$I_{PP} = 1\text{ A}$	-	-	7	V
		$I_{PP} = 18\text{ A}$	-	-	20	V
	PESD5V0S1UB	$I_{PP} = 1\text{ A}$	-	-	9	V
		$I_{PP} = 15\text{ A}$	-	-	20	V
	PESD12VS1UB	$I_{PP} = 1\text{ A}$	-	-	19	V
		$I_{PP} = 5\text{ A}$	-	-	35	V
	PESD15VS1UB	$I_{PP} = 1\text{ A}$	-	-	23	V
		$I_{PP} = 5\text{ A}$	-	-	40	V
	PESD24VS1UB	$I_{PP} = 1\text{ A}$	-	-	36	V
		$I_{PP} = 3\text{ A}$	-	-	70	V

**Characteristics...continued**
 $T_{amb} = 25^{\circ}\text{C}$  unless otherwise specified

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$R_{diff}$	differential resistance					
	PESD3V3S1UB	$I_R = 1 \text{ mA}$	-	-	400	$\Omega$
	PESD5V0S1UB	$I_R = 1 \text{ mA}$	-	-	80	$\Omega$
	PESD12VS1UB	$I_R = 1 \text{ mA}$	-	-	200	$\Omega$
	PESD15VS1UB	$I_R = 1 \text{ mA}$	-	-	225	$\Omega$
	PESD24VS1UB	$I_R = 0.5 \text{ mA}$	-	-	300	$\Omega$

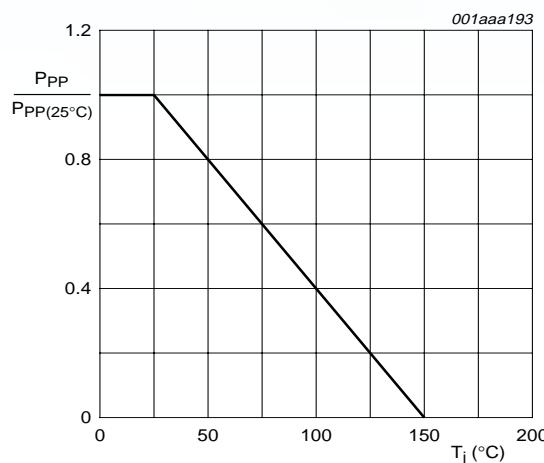
[1] Non-repetitive current pulse 8/20  $\mu\text{s}$  exponentially decay waveform; see Figure 1.


 $T_{amb} = 25^{\circ}\text{C}$ 
 $t_p = 8/20 \mu\text{s}$  exponentially decay waveform,  
see Figure 1

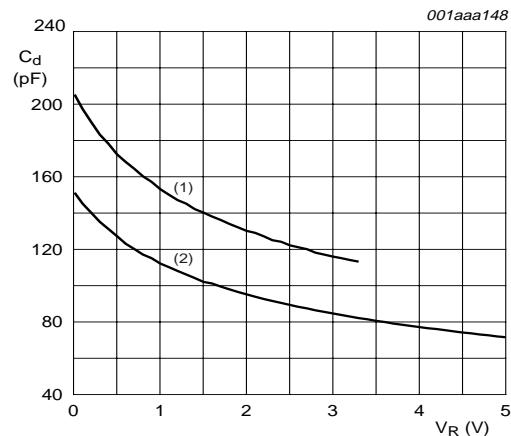
(1) PESD3V3S1UB and PESD5V0S1UB

(2) PESD12VS1UB, PESD15VS1UB; PESD24VS1UB

**Fig 3. Peak pulse power dissipation as a function of pulse time; typical values**



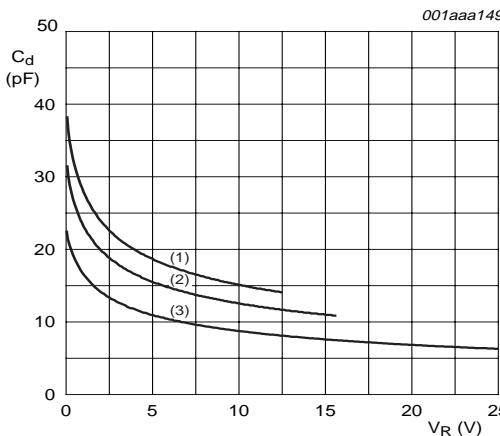
**Fig 4. Relative variation of peak pulse power as a function of junction temperature; typical values**


 $f = 1 \text{ MHz}; T_{amb} = 25^{\circ}\text{C}$ 

(1) PESD3V3S1UB

(2) PESD5V0S1UB

**Fig 5. Diode capacitance as a function of reverse voltage; typical values**

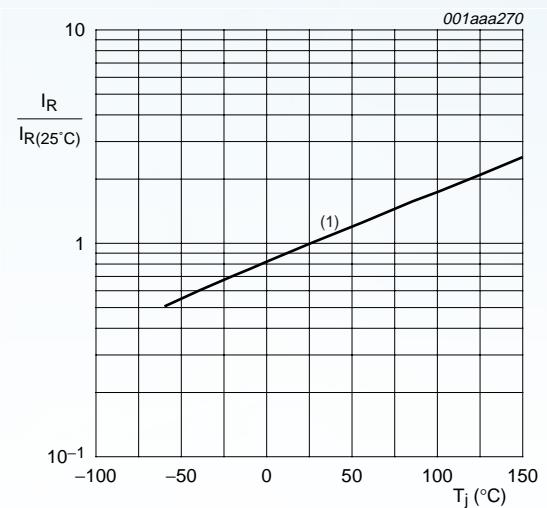

 $f = 1 \text{ MHz}; T_{amb} = 25^{\circ}\text{C}$ 

(1) PESD12VS1UB

(2) PESD15VS1UB

(3) PESD24VS1UB

**Fig 6. Diode capacitance as a function of reverse voltage; typical values**



(1) PESD3V3S1UB;  $V_{RWM} = 3.3 \text{ V}$

PESD5V0S1UB;  $V_{RWM} = 5 \text{ V}$

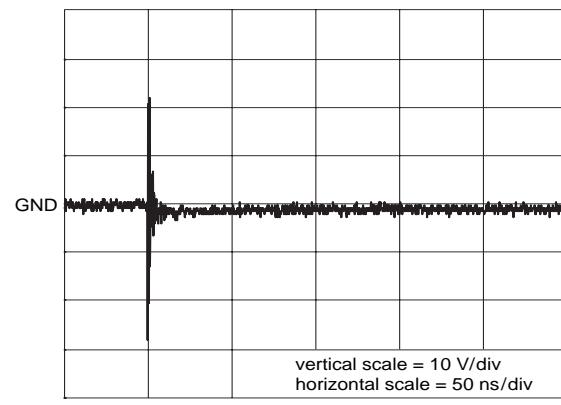
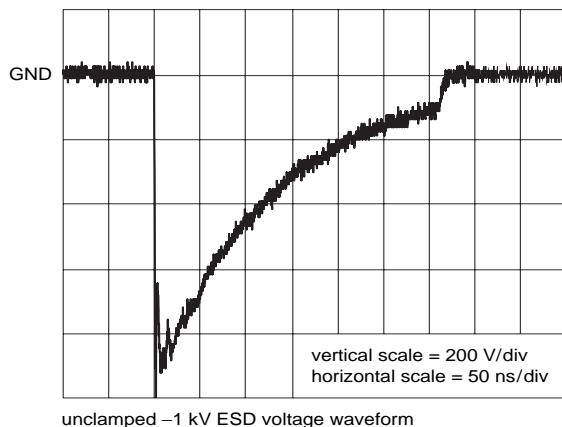
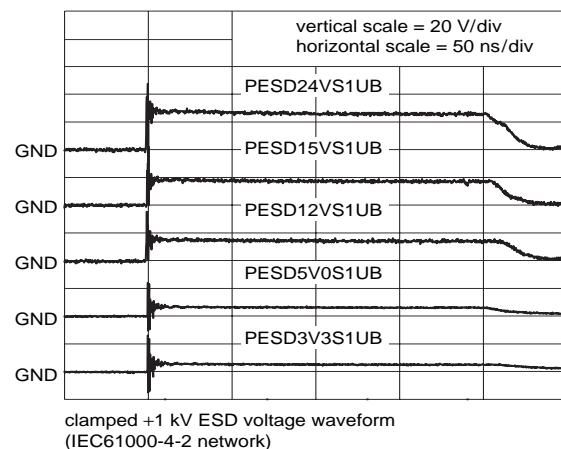
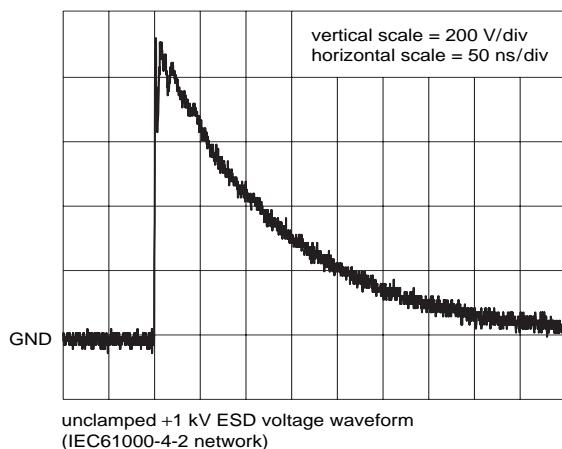
$I_R$  is less than 10 nA at 150 °C for:

PESD12VS1UB;  $V_{RWM} = 12 \text{ V}$

PESD15VS1UB;  $V_{RWM} = 15 \text{ V}$

PESD24VS1UB;  $V_{RWM} = 24 \text{ V}$

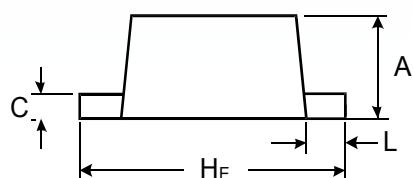
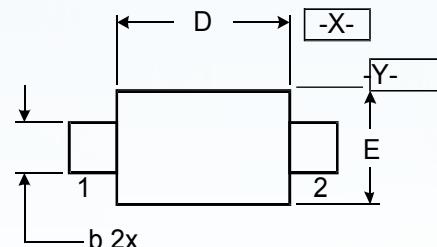
**Fig 7. Relative variation of reverse leakage current as a function of junction temperature; typical values**



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**Fig 8. ESD clamping test setup and waveforms**

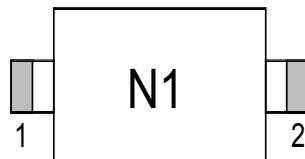
## Outline Drawing – SOD-523



### DIMENSIONS

SYMBOL	MILLIMETER		INCHES	
	MIN	MAX	MIN	MAX
A	0.50	0.70	0.020	0.028
b	0.25	0.35	0.010	0.014
C	0.07	0.20	0.0028	0.0079
D	1.10	1.30	0.043	0.051
E	0.70	0.90	0.028	0.035
H <sub>E</sub>	1.50	1.70	0.059	0.067
L	0.15	0.25	0.006	0.010

## Marking



## Ordering information

Order code	Marking	Package	Baseqty	Deliverymode
PESD3V3S1UB	N1	SOD-523	3000	Tape and reel
PESD5V0S1UB	N2	SOD-523	3000	Tape and reel
PESD12VS1UB	N3	SOD-523	3000	Tape and reel
PESD15VS1UB	N4	SOD-523	3000	Tape and reel
PESD24VS1UB	N5	SOD-523	3000	Tape and reel

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